

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	120	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Current	I _C	1	A
Peak Collector Current	I _{CM}	2	A
Peak Dissipation at T _A = +25°C	P _D	1	W

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

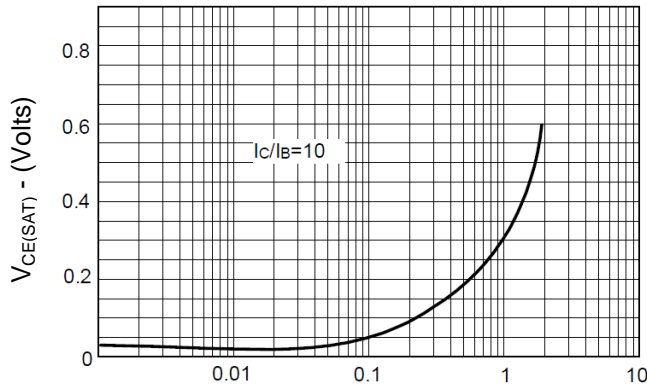
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic (Note 5)	Symbol	Min	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	120	—	V	I _C = 100μA, I _B = 0
Collector-Emitter Breakdown Voltage	BV _{CEO}	100	—	V	I _C = 10mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	5	—	V	I _E = 100μA, I _C = 0
DC Current Gain	h _{FE}	40	200	—	V _{CE} = 10V, I _C = 150mA, V _{CE} = 10V, I _C = 1A
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	0.7	V	I _C = 150mA, I _B = 15mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	1.3	V	I _C = 150mA, I _B = 15mA
Collector-Cutoff Current	I _{CBO}	—	0.1	μA	V _{CB} = 100V
Emitter-Cutoff Current	I _{EBO}	—	0.1	μA	V _{EB} = 4V
Gain Bandwidth Product	f _T	150	—	MHz	V _{CE} = 10V, I _C = 50mA, f = 100MHz
Collector-Base Capacitance	C _{CBO}	—	3.0	pF	V _{CB} = 10V, f = 1MHz
Output Capacitance	C _{OBO}	—	15	pF	V _{CB} = 10V, f = 1MHz

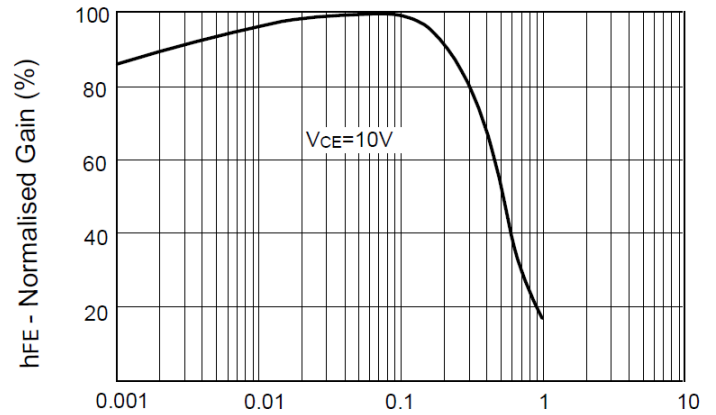
Notes: 5. Short duration pulse test used to minimize self-heating effect.
6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



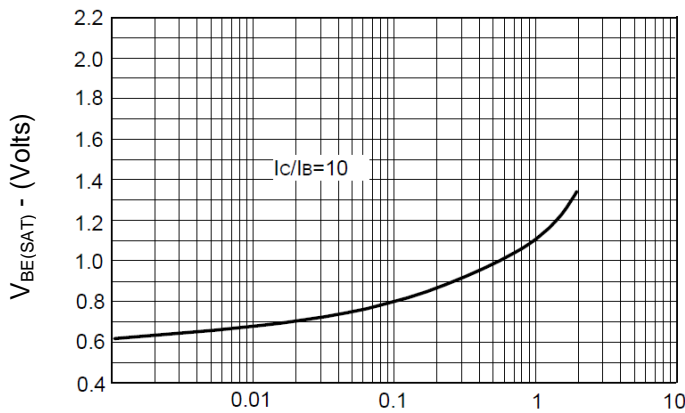
I_C - Collector Current (Amps)

$V_{CE(SAT)} \text{ v } I_C$



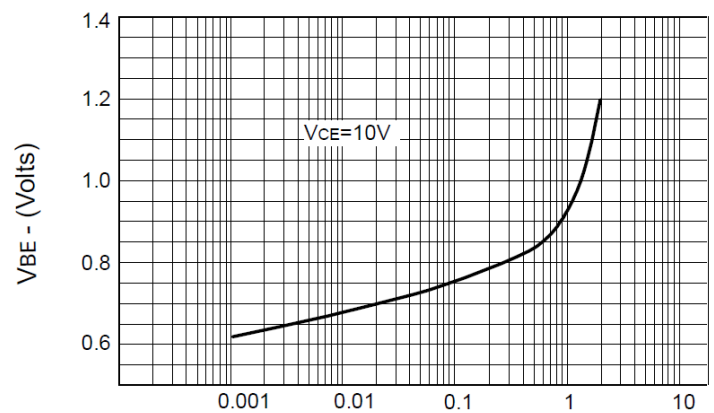
I_C - Collector Current (Amps)

$hFE \text{ v } I_C$



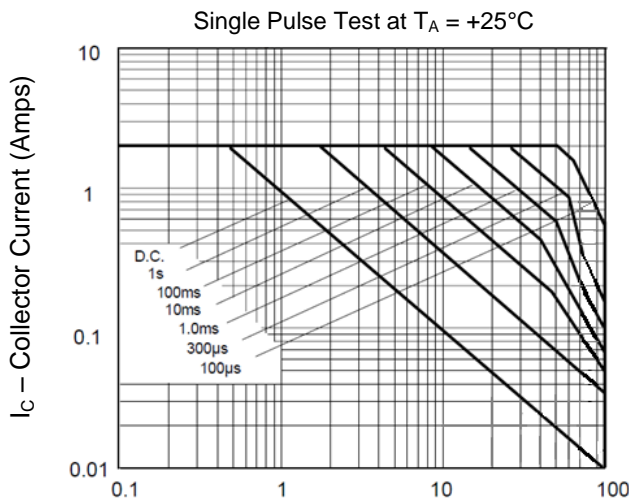
I_C - Collector Current (Amps)

$V_{BE(SAT)} \text{ v } I_C$



I_C - Collector Current (Amps)

$V_{BE(ON)} \text{ v } I_C$

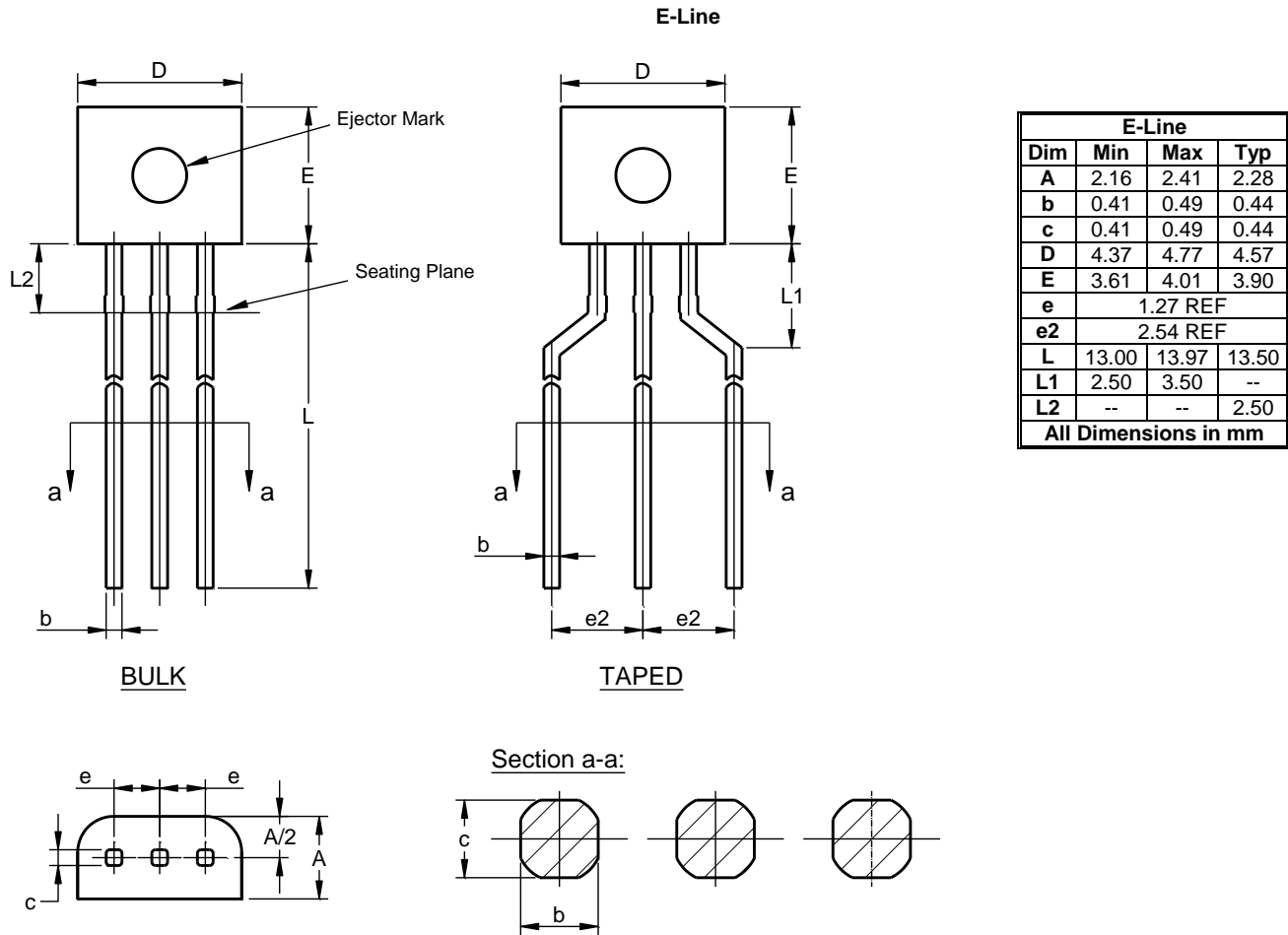


V_{CE} - Collector Voltage (Volts)

Safe Operating Area

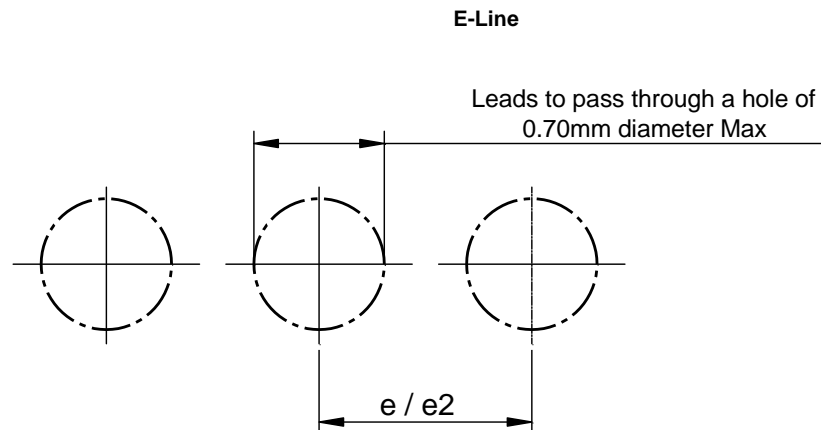
Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Suggested Pad Hole

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